PDTC144V series

NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 10 k Ω

Rev. 04 — 16 November 2009

Product data sheet

1. Product profile

1.1 General description

NPN resistor-equipped transistors.

Table 1. Product overview

| Type number | Package | Package | | |
|--------------|---------------|---------|-----------|--|
| | NXP | JEITA | | |
| PDTC144VE | SOT416 | SC-75 | PDTA144VE | |
| PDTC144VK | SOT346 | SC-59A | PDTA144VK | |
| PDTC144VM | SOT883 | SC-101 | PDTA144VM | |
| PDTC144VS[1] | SOT54 (TO-92) | SC-43A | PDTA144VS | |
| PDTC144VT | SOT23 | - | PDTA144VT | |
| PDTC144VU | SOT323 | SC-70 | PDTA144VU | |

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2).

1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

1.3 Applications

- General-purpose switching and amplification
- Inverter and interface circuits

Circuit drivers

1.4 Quick reference data

Table 2. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------|---------------------------|------------|------|------|------|------|
| V_{CEO} | collector-emitter voltage | open base | - | - | 50 | V |
| Io | output current (DC) | | - | - | 100 | mA |
| R1 | bias resistor 1 (input) | | 33 | 47 | 61 | kΩ |
| R2/R1 | bias resistor ratio | | 0.17 | 0.21 | 0.26 | |



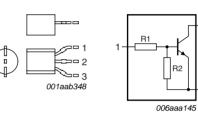
2. Pinning information

Table 3. Pinning

| | 3 | | |
|-------|--------------------|--------------------|---|
| Pin | Description | Simplified outline | Symbol |
| SOT54 | | | |
| 1 | input (base) | | |
| 2 | output (collector) | | 1 2 |
| 3 | GND (emitter) | 001aab347 | 1 R1 R2 |

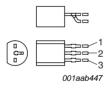
SOT54A

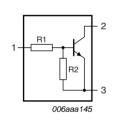
| 1 | input (base) |
|---|--------------------|
| 2 | output (collector) |
| 3 | GND (emitter) |



SOT54 variant

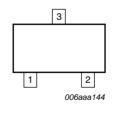
| 1 | input (base) |
|---|--------------------|
| 2 | output (collector) |
| 3 | GND (emitter) |

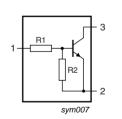




SOT23, SOT323, SOT346, SOT416

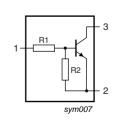
| 1 | input (base) |
|---|--------------------|
| 2 | GND (emitter) |
| 3 | output (collector) |





SOT883

| 1 | input (base) |
|---|--------------------|
| 2 | GND (emitter) |
| 3 | output (collector) |



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NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 10 k Ω

Ordering information 3.

Ordering information Table 4.

| Package | | | | |
|---------|---|---|--|--|
| Name | Description | Version | | |
| SC-75 | plastic surface mounted package; 3 leads | SOT416 | | |
| SC-59A | plastic surface mounted package; 3 leads | SOT346 | | |
| SC-101 | leadless ultra small plastic package; 3 solder lands; body 1.0 \times 0.6 \times 0.5 mm | SOT883 | | |
| SC-43A | plastic single-ended leaded (through hole) package; 3 leads | SOT54 | | |
| - | plastic surface mounted package; 3 leads | SOT23 | | |
| SC-70 | plastic surface mounted package; 3 leads | SOT323 | | |
| | Name SC-75 SC-59A SC-101 SC-43A | Name Description SC-75 plastic surface mounted package; 3 leads SC-59A plastic surface mounted package; 3 leads SC-101 leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.5 mm SC-43A plastic single-ended leaded (through hole) package; 3 leads - plastic surface mounted package; 3 leads | | |

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9).

Marking

Product data sheet

Table 5. Marking codes

| Table of Market Specific | |
|--------------------------|-----------------------------|
| Type number | Marking code ^[1] |
| PDTC144VE | 18 |
| PDTC144VK | 29 |
| PDTC144VM | G6 |
| PDTC144VS | TC144V |
| PDTC144VT | *AA |
| PDTC144VU | *18 |

^{[1] * = -:} made in Hong Kong

^{* =} p: made in Hong Kong

^{* =} t: made in Malaysia

^{* =} W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|---------------------------|-----------------------------|--------------|------------|------|
| V_{CBO} | collector-base voltage | open emitter | - | 50 | V |
| V_{CEO} | collector-emitter voltage | open base | - | 50 | V |
| V_{EBO} | emitter-base voltage | open collector | - | 15 | V |
| V_{I} | input voltage | | | | |
| | positive | | - | +40 | V |
| | negative | | - | –15 | V |
| I _O | output current (DC) | | - | 100 | mA |
| I _{CM} | peak collector current | | - | 100 | mA |
| P _{tot} | total power dissipation | | | | |
| | SOT416 | $T_{amb} \leq 25 ^{\circ}C$ | <u>[1]</u> - | 150 | mW |
| | SOT346 | $T_{amb} \leq 25 ^{\circ}C$ | <u>[1]</u> - | 250 | mW |
| | SOT883 | $T_{amb} \le 25 ^{\circ}C$ | [2][3] | 250 | mW |
| | SOT54 | $T_{amb} \le 25 ^{\circ}C$ | <u>[1]</u> - | 500 | mW |
| | SOT23 | $T_{amb} \le 25 ^{\circ}C$ | <u>[1]</u> - | 250 | mW |
| | SOT323 | $T_{amb} \le 25 ^{\circ}C$ | [1] - | 200 | mW |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | - | 150 | °C |
| T _{amb} | ambient temperature | | -65 | +150 | °C |

^[1] Refer to standard mounting conditions.

6. Thermal characteristics

Table 7. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------|---|-------------|--------------|-----|-----|------|
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air | | | | |
| | SOT416 | | <u>[1]</u> - | - | 833 | K/W |
| | SOT346 | | <u>[1]</u> - | - | 500 | K/W |
| | SOT883 | | [2][3] | - | 500 | K/W |
| | SOT54 | | <u>[1]</u> _ | - | 250 | K/W |
| | SOT23 | | <u>[1]</u> _ | - | 500 | K/W |
| | SOT323 | | <u>[1]</u> _ | - | 625 | K/W |

^[1] Refer to standard mounting conditions.

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^[2] Reflow soldering is the only recommended soldering method.

^[3] Refer to SOT883 standard mounting conditions; FR4 printed-circuit board with 60 µm copper strip line.

^[2] Reflow soldering is the only recommended soldering method.

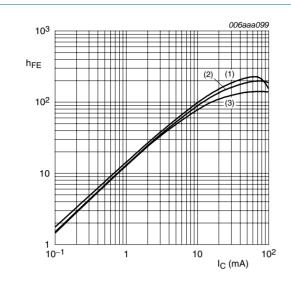
^[3] Refer to SOT883 standard mounting conditions; FR4 printed-circuit board with 60 μm copper strip line.

7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------------------|---|--|------|------|------|------|
| I _{CBO} | collector-base cut-off current | $V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$ | - | - | 100 | nA |
| I _{CEO} | collector-emitter | $V_{CE} = 30 \text{ V}; I_B = 0 \text{ A}$ | - | - | 1 | μΑ |
| cut-off current | $V_{CE} = 30 \text{ V; } I_{B} = 0 \text{ A;}$ $T_{j} = 150 \text{ °C}$ | - | - | 50 | μΑ | |
| I _{EBO} | emitter-base cut-off current | $V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$ | - | - | 150 | μΑ |
| h _{FE} | DC current gain | $V_{CE} = 5 \text{ V}; I_{C} = 5 \text{ mA}$ | 40 | - | - | |
| V _{CEsat} | collector-emitter saturation voltage | $I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$ | - | - | 150 | mV |
| $V_{I(off)}$ | off-state input voltage | $V_{CE} = 5 \text{ V}; I_{C} = 100 \mu\text{A}$ | - | 3.1 | 1 | V |
| V _{I(on)} | on-state input voltage | $V_{CE} = 300 \text{ mV}; I_C = 2 \text{ mA}$ | 6 | 3.8 | - | V |
| R1 | bias resistor 1 (input) | | 33 | 47 | 61 | kΩ |
| R2/R1 | bias resistor ratio | | 0.17 | 0.21 | 0.26 | |
| C _c | collector capacitance | $V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz | - | - | 2 | pF |



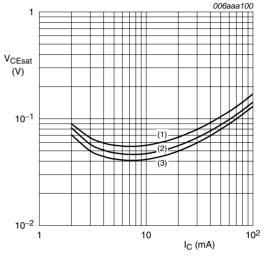
$$V_{CE} = 5 V$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 1. DC current gain as a function of collector current; typical values



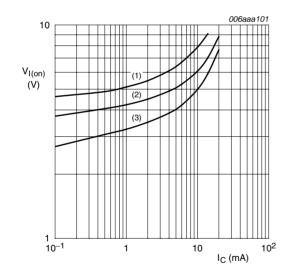
$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 2. Collector-emitter saturation voltage as a function of collector current; typical values



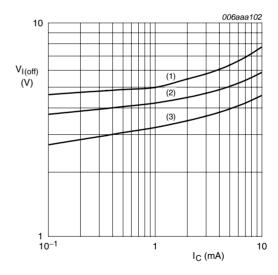
$$V_{CE} = 0.3 \text{ V}$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig 3. On-state input voltage as a function of collector current; typical values



$$V_{CE} = 5 V$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

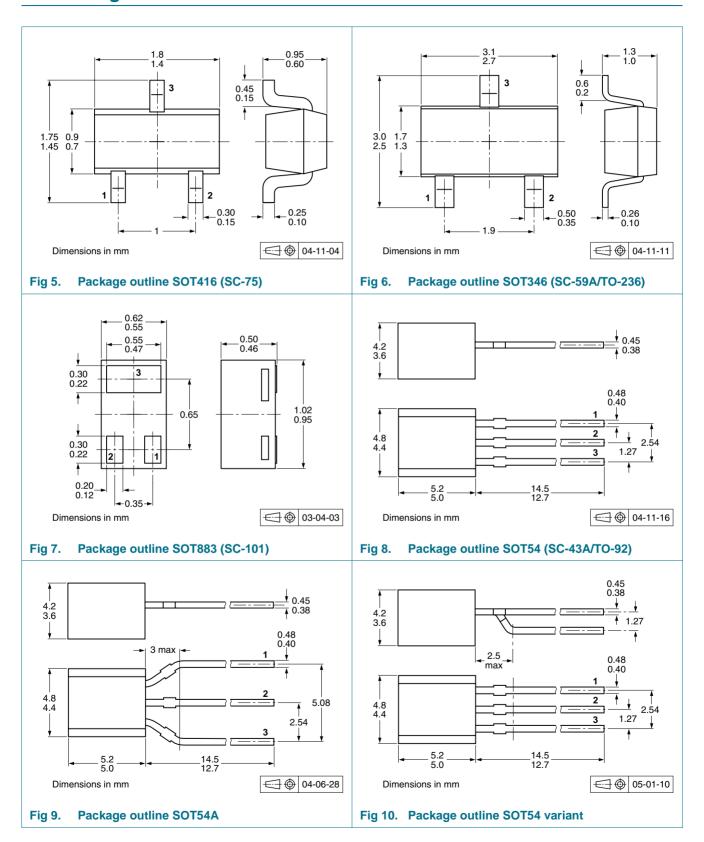
(2)
$$T_{amb} = 25 \, ^{\circ}C$$

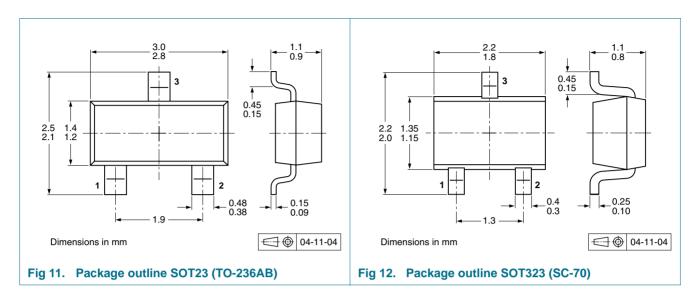
(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig 4. Off-state input voltage as a function of collector current; typical values

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8. Package outline





9. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number | Package | Description | Packing quantity | | |
|-------------|---------------|--------------------------------|------------------|------|-------|
| | | | 3000 | 5000 | 10000 |
| PDTC144VE | SOT416 | 4 mm pitch, 8 mm tape and reel | -115 | - | -135 |
| PDTC144VK | SOT346 | 4 mm pitch, 8 mm tape and reel | -115 | - | -135 |
| PDTC144VM | SOT883 | 2 mm pitch, 8 mm tape and reel | - | - | -315 |
| PDTC144VS | SOT54 | bulk, straight leads | - | -412 | - |
| | SOT54A | tape and reel, wide pitch | - | - | -116 |
| | | tape ammopack, wide pitch | - | - | -126 |
| | SOT54 variant | bulk, delta pinning | - | -112 | - |
| PDTC144VT | SOT23 | 4 mm pitch, 8 mm tape and reel | -215 | - | -235 |
| PDTC144VU | SOT323 | 4 mm pitch, 8 mm tape and reel | -115 | - | -135 |

^[1] For further information and the availability of packing methods, see Section 12.



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NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 10 k Ω

10. Revision history

Table 10. Revision history

Product data sheet

| | • | | | | |
|----------------|---|----------------------|---------------|----------------|--|
| Document ID | Release date | Data sheet status | Change notice | Supersedes | |
| PDTC144V_SER_4 | 20091116 | Product data sheet | - | PDTC144V_SER_3 | |
| Modifications: | This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content. | | | | |
| PDTC144V_SER_3 | 20050215 | Product data sheet | - | PDTC144VT_2 | |
| PDTC144VT_2 | 20040511 | Objective data sheet | - | PDTC144VT_1 | |
| PDTC144VT_1 | 20040305 | Objective data sheet | - | - | |

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11.1 Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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PDTC144V series

NPN resistor-equipped transistors; $R1 = 47 \text{ k}\Omega$, $R2 = 10 \text{ k}\Omega$

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